

## Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	$I_D$
85V	4.2mΩ@10V	110A

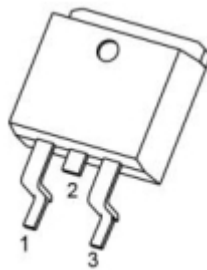
## Feature

- Fast Switching
- Low Gate Charge and Rdson
- Low Reverse transfer capacitances
- 100% Single Pulse avalanche energy Test

## Applications

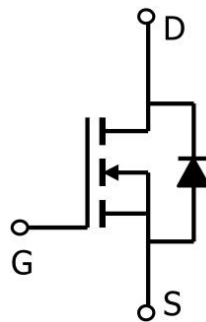
- Power switching application
- DC-DC Converter
- PWM Application

## Package

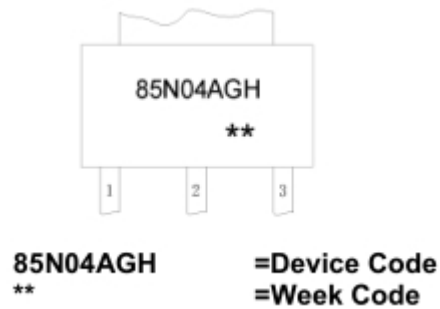


TO-263(1:G 2:D 3:S)

## Circuit diagram



## Marking



## Absolute maximum ratings

(T<sub>a</sub>=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DS</sub>	85	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Continuous Drain Current(Tc=25°C)	I <sub>D</sub>	110	A
Pulsed Drain Current <sup>2</sup>	I <sub>DM</sub>	440	A
Single Pulse Avalanche Energy <sup>3</sup>	E <sub>AS</sub>	529	mJ
Total Power Dissipation <sup>4</sup> (Tc=25°C)	P <sub>D</sub>	140	W
Thermal Resistance Junction-Case <sup>1</sup>	R <sub>θJC</sub>	0.89	°C/W
Storage Temperature Range	T <sub>STG</sub>	-55 to 150	°C
Operating Junction Temperature Range	T <sub>J</sub>	-55 to 150	°C

## Electrical characteristics

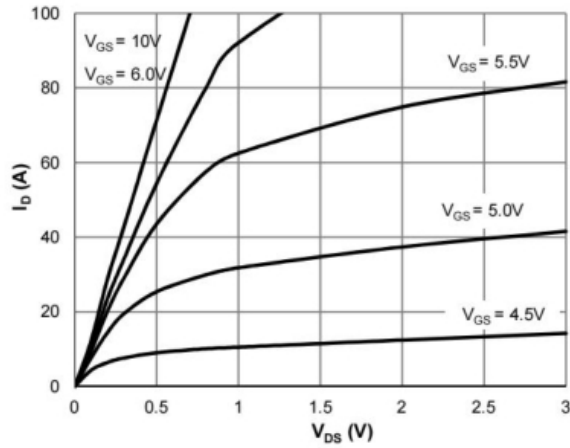
( $T_A=25^{\circ}\text{C}$ , unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	BV (BR)DSS	V <sub>GS</sub> = 0V, I <sub>D</sub> =250μA	85			V
Drain-Source Leakage Current	I <sub>DSS</sub>	V <sub>DS</sub> =85V, V <sub>GS</sub> = 0V , T <sub>J</sub> =25°C			1	uA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> = 0V			±100	uA
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	2.0	2.8	4.0	V
Static Drain-Source On-Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A		4.2	5.5	mΩ
Dynamic Characteristics						
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> =40V, V <sub>GS</sub> =0V, f=1MHz		3451		pF
Output capacitance	C <sub>oss</sub>			677		
Reverse transfer capacitance	C <sub>rss</sub>			18		
Switching Characteristics						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =40V, V <sub>GS</sub> =10V, I <sub>D</sub> =20A		26		pF
Gate-Source Charge	Q <sub>gs</sub>			10		
Gate-Drain Charge	Q <sub>gd</sub>			11		
Turn-on Delay Time	T <sub>d(on)</sub>	V <sub>DD</sub> =40V, V <sub>GS</sub> =10V, R <sub>G</sub> =6Ω , I <sub>D</sub> =20A		16		nS
Turn-on Rise Time	T <sub>r</sub>			35		
Turn-Off Delay Time	T <sub>d(off)</sub>			33		
Turn-Off Fall Time	t <sub>f</sub>			22		
Drain-Source Body Diode Characteristics						
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> = 1A, V <sub>GS</sub> = 0V, T <sub>J</sub> =25°C			1.2	V

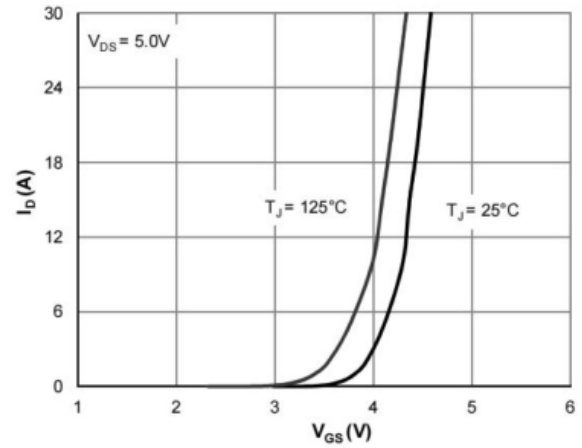
### Note:

1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.
2. The data tested by pulsed , pulse width  $\leq 300\mu s$  , duty cycle  $\leq 2\%$
3. The EAS data shows Max. rating . The test condition is  $V_{DD}=42.5V, V_{GS}=10V, L=0.5mH, I_{AS}=46A$
4. The power dissipation is limited by  $150^{\circ}\text{C}$  junction temperature

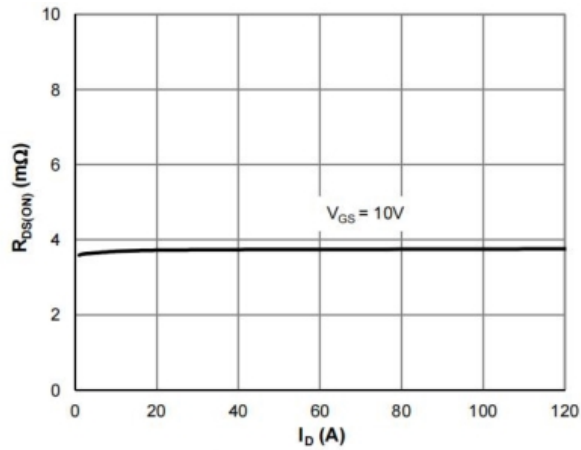
## Typical Characteristics



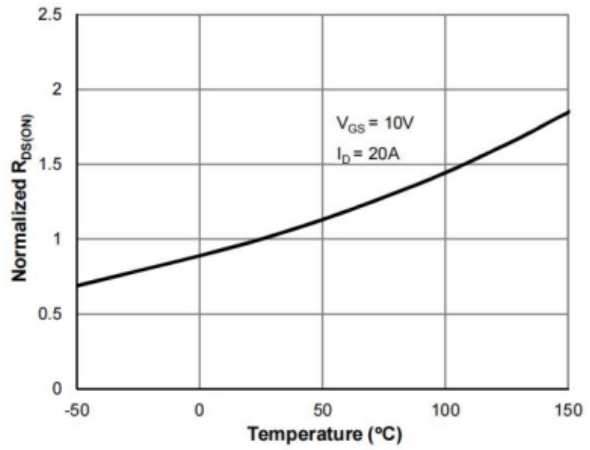
Typical Output Characteristics



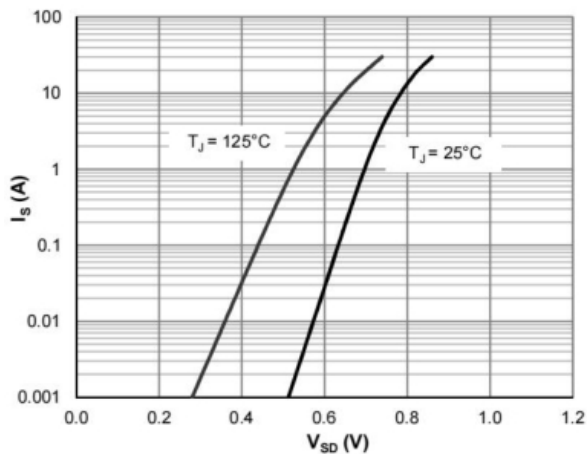
Transfer Characteristics



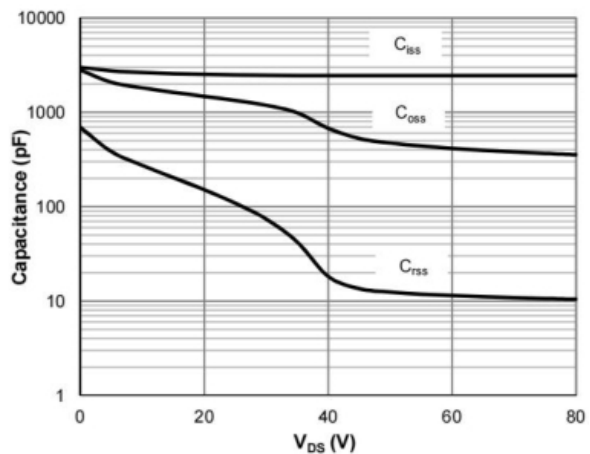
On-Resistance vs. Drain Current



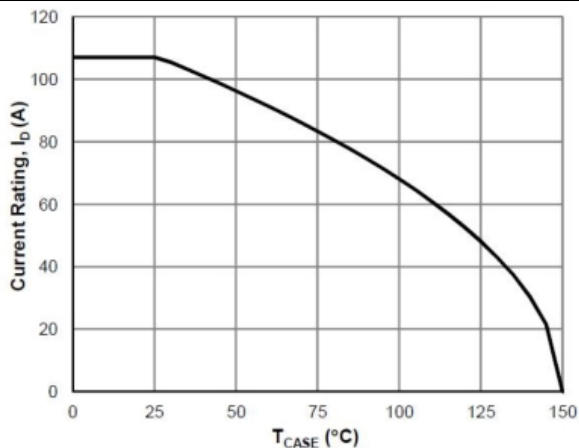
On-Resistance vs. Junction Temperature



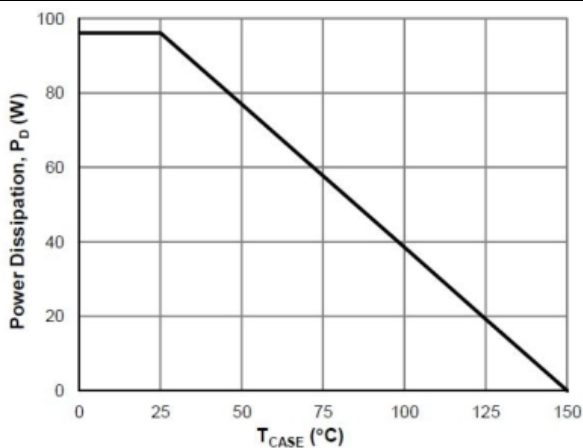
Body-Diode Characteristics



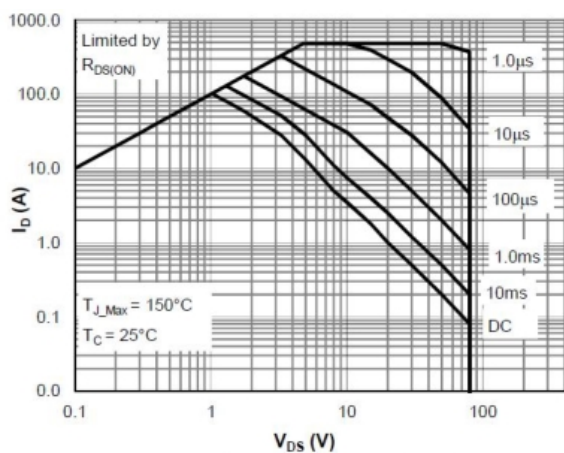
Capacitance Characteristics



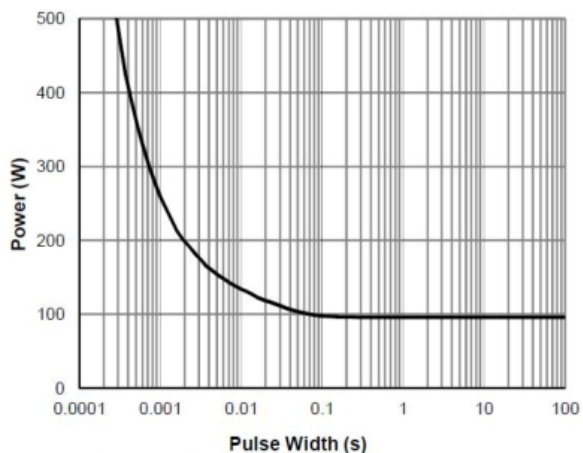
Current De-rating



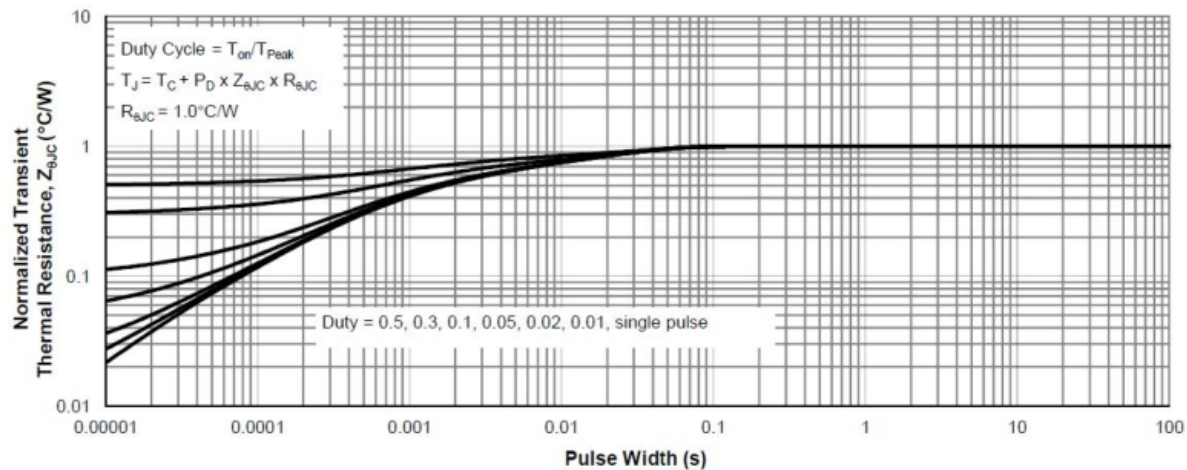
Power De-rating



Maximum Safe Operating Area

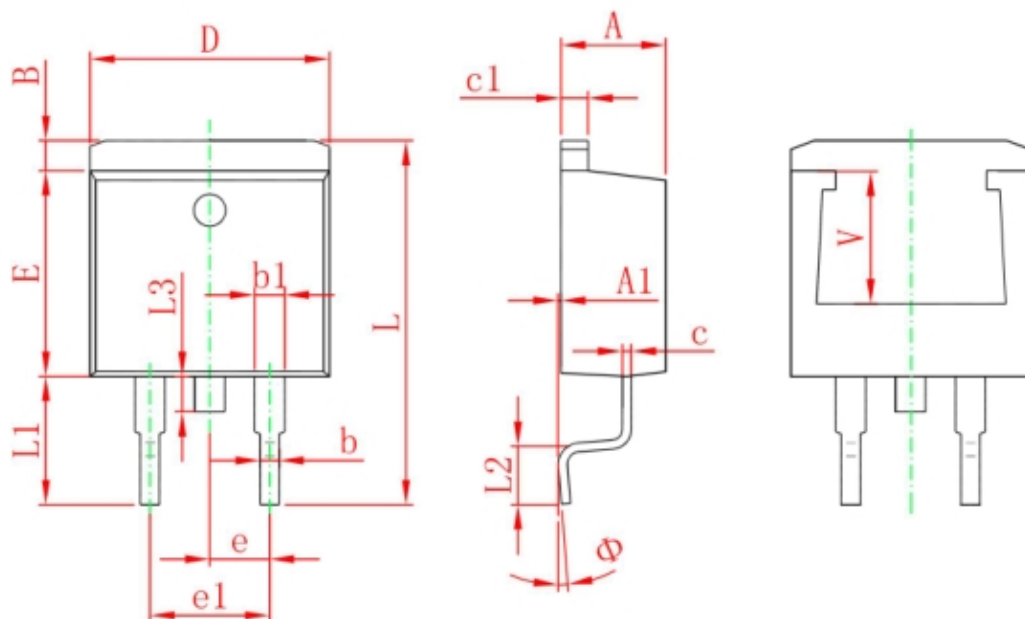


Single Pulse Power Rating, Junction-to-Case



Normalized Maximum Transient Thermal Impedance

## TO-263 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.470	4.670	0.176	0.184
A1	0.000	0.150	0.000	0.006
B	1.120	1.420	0.044	0.056
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
c	0.310	0.530	0.012	0.021
c1	1.170	1.370	0.046	0.054
D	10.010	10.310	0.394	0.406
E	8.500	8.900	0.335	0.350
e	2.540 TYP.		0.100 TYP.	
e1	4.980	5.180	0.196	0.204
L	14.940	15.500	0.588	0.610
L1	4.950	5.450	0.195	0.215
L2	2.340	2.740	0.092	0.108
L3	1.300	1.700	0.051	0.067
Φ	0°	8°	0°	8°
V	5.600 REF.		0.220 REF.	